

# UTC UNISONIC TECHNOLOGIES CO., LTD

MCR08 **SCR Preliminary** 

# SENSITIVE GATE SILICON **CONTROLLED RECTIFIER**

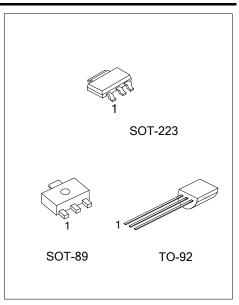
#### **DESCRIPTION**

The UTC MCR08 is a 0.8A SCR, it uses UTC's advanced technology to provide customers with sensitive gate trigger current, etc.

The UTC MCR08 is suitable for line powered consumer applications such as relay and lamp drivers, small motor controls, gate drivers for larger thyristors, and sensing and detection circuits.

### **FEATURES**

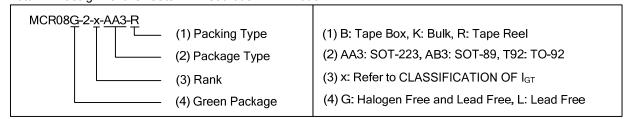
- \* Blocking voltage to 600V
- \* Sensitive gate trigger current
- \* Glass passivated surface for reliability and uniformity



# **ORDERING INFORMATION**

Ordering Number		Dackage	Pin assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
-	MCR08G-2-x-AA3-R	SOT-223	K	Α	G	Tape Reel	
-	MCR08G-2-x-AB3-R	SOT-89	G	Α	K	Tape Reel	
MCR08L-2-x-T92-B	MCR08G-2-x-T92-B	TO-92	K	G	Α	Tape Box	
MCR08L-2-x-T92-K	MCR08G-2-x-T92-K	TO-92	K	G	Α	Bulk	
-	MCR08G-6-x-AA3-R	SOT-223	K	Α	G	Tape Reel	
-	MCR08G-6-x-AB3-R	SOT-89	G	Α	K	Tape Reel	
MCR08L-6-x-T92-B	MCR08G-6-x-T92-B TO-92 K G		Α	Tape Box			
MCR08L-6-x-T92-K	MCR08G-6-x-T92-K	TO-92	K	G	Α	Bulk	

Note: Pin assignment: G: Gate K: Cathode A: Anode



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# ■ MARKING

Package	MCR100-2	MCR100-6		
SOT-223	MCR08G  -2 □□□□  Data Code	MCR08G -6 □□□□ → Data Code		
SOT-89	Data Code	Data Code		
TO-92	UTC MCR08	UTC MCR08   L: Lead Free G: Halogen Free Data Code		

# ■ ABSOLUTE MAXIMUM RATINGS (T<sub>J</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	RATINGS	UNIT
Peak Repetitive Off-State Voltage (Note 1)	MCR08-2	$V_{DRM}$ ,	200	<b>V</b>
(Sine Wave, R <sub>GK</sub> =1kΩ T <sub>J</sub> =25~110°C)	MCR08-6	$V_{RRM}$	600	<b>&gt;</b>
On-State Current RMS (All Conduction Angles, T <sub>C</sub> =80°C)		I <sub>T(RMS)</sub>	0.8	Α
Peak Non-repetitive Surge Current (1/2 Cycle Sine Wave, 60Hz, T <sub>C</sub> =25°C)		I <sub>TSM</sub>	8.0	Α
Circuit Fusing Considerations (t =8.3ms)		l <sup>2</sup> t	0.4	$A^2s$
Forward Peak Gate Power (T <sub>C</sub> =80°C, t =1.0µs)		$P_{GM}$	0.1	W
Average Gate Power (T <sub>C</sub> =80°C, t=8.3ms)		$P_{G(AV)}$	0.01	W
Operating Junction Temperature		Τ <sub>J</sub>	-40~+110	°C
Storage Temperature		T <sub>STG</sub>	-40~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### **■ THERMAL DATA**

F	PARAMETER	SYMBOL	MAX	UNIT
	SOT-2	23	180	°C/W
Junction to Ambient	SOT-8	9 θ <sub>JA</sub>	400	°C/W
	TO-92		200	°C/W

# ■ ELECTRICAL CHARACTERISTICS (T<sub>C</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Peak Repetitive Forward or Reverse		V <sub>AK</sub> =Rated V <sub>DRM</sub> or	T <sub>J</sub> =25°C			10	μΑ
Blocking Current (Note 3)	$I_{DRM}, I_{RRM}$	$V_{RRM}$ , $R_{GK}$ =1k $\Omega$ $T_J$ =110°C				200	μΑ
ON CHARACTERISTICS							
Peak Forward On-State Voltage (Note 2)	$V_{TM}$	I <sub>T</sub> =1.0A Peak				1.7	V
Gate Trigger Current (Continuous dc) (Note 4)	I <sub>GT</sub>	V <sub>AK</sub> =12Vdc, R <sub>L</sub> =100Ω				200	μΑ
Holding Current (Note 3)	I <sub>H</sub>	V <sub>AK</sub> =12Vdc, Initiating Current=20mA				5.0	mA
Gate Trigger Voltage (Continuous dc) (Note 4)	$V_{GT}$	V <sub>AK</sub> =12Vdc, R <sub>L</sub> =100Ω				0.8	V
Turn-On Time	t <sub>gt</sub>	V <sub>AK</sub> =12Vdc, I <sub>TM</sub> =5Adc, I <sub>GT</sub> =5mA			1.25		μs
DYNAMIC CHARACTERISTICS							
Critical Rate-of-Rise of Off State Voltage	dv/dt	$V_{pk}$ =Rated $V_{DRM}$ , $T_C$ =110°C, $R_{GK}$ =1k $\Omega$ , Exponential Method				V/µs	

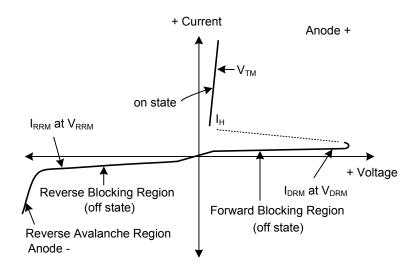
Notes: 1. V<sub>DRM</sub> and V<sub>RRM</sub> for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant source such that the voltage ratings of the devices are exceeded.

- 2. Pulse Test: Pulse width≤300µs, Duty cycle≤2%.
- 3.  $R_{\text{GK}}$ =1000 $\Omega$  is included in measurement.
- 4.  $R_{\text{GK}}$  is not included in measurement.

# ■ VOLTAGE CURRENT CHARACTERISTIC OF SCR

PARAMETER	SYMBOL
Peak Repetitive Off Stat Forward Voltage	$V_{DRM}$
Peak Forward Blocking Current	I <sub>DRM</sub>
Peak Repetitive Off State Reverse Voltage	$V_{RRM}$
Peak Reverse Blocking Current	I <sub>RRM</sub>
Peak On State Voltage	$V_{TM}$
Holding Current	IΗ

#### Voltage Current Characteristic of SCR



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